MSS40, MSS50

Back to back SCR module

Table 1. Main features

Symbol	Value	Unit
I _{T(RMS)}	55 and 70	Α
V _{DRM} /V _{RRM}	800 and 1200	V
I _{GT}	50	mA

Description

Packaged in ISOTOP modules, the MSS40 / MSS50 Series is based on two back-to-back SCR configurations, providing high noise immunity. They are suitable for high power applications such as solid state relays, heating control systems, welding equipment, motor control circuits...

The compactness of the ISOTOP package allows high power density and optimized power bus connections. Thanks to their internal ceramic pad, they provide high voltage insulation (2500 V_{RMS}), complying with UL standards (File ref: E81734).

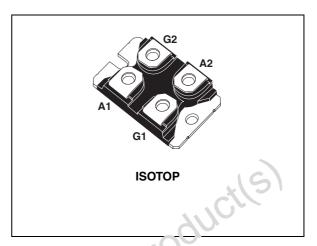
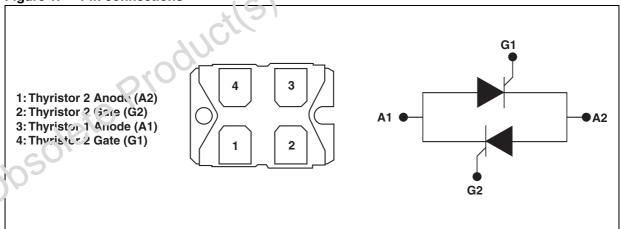


Table 2. Order cons

Part numbers	Marking
MSS412-1200	MSS40-1200
M3S50-800	MSS50-800
MSS50-1200	MSS50-1200

Figure 1. Pin connections



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Characteristics MSS40, MSS50

1 Characteristics

Table 3. Absolute ratings (limiting values)

Symbol	Parameter				Value		
Symbol					MSS50	Unit	
V _{DRM} /V _{RRM}	Repetitive peak off-state voltage			1200	800 1200	V	
1			T _c = 80° C	55		Α	
I _T (RMS)	RMS on-state current	T _c = 85° C		70			
1.	Non repetitive surge peak on-state		T 05° C	420	630		
I _{TSM}	current	$t_p = 20 \text{ ms}$	T _j = 25° C	400	600	Α	
l ² t	I ² t Value for fusing	t _p = 10 ms	T _j = 25° C	800	1800	A ² s	
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $I_r \le 100 \text{ ns}$ $I_j = 125 \text{ m}$		T _j = 125° C	5	0	A/µs	
I _{GM}	Peak gate current $t_p = 20 \mu s$ $T_j = 125^{\circ} C$		T _j = 125° C	4	4	A	
P _{G(AV)}	Average gate power dissipation $T_j = 125^{\circ} C$			1	W		
T _{stg} T _j	Storage junction temperature range Operating junction temperature range			+ 150 + 125	° C		
V_{RGM}	Maximum peak reverse gate voltage		0	(i	5	V	

Table 4. Electrical characteristics ($T_i = 25^{\circ}$ C, unless otherwise specified)

Symbol	Tost Condition	7/8,	Va	lue	Unit		
Symbol	Test Conditions			MSS40	MSS50	Jille	
1			MIN. 5		5	mA	
I _{GT}	$V_D = 12 \text{ V}$ $R_L = 33 \Omega$		MAX.	5	0	IIIA	
V _{GT}	16		MAX.	1.	.3	V	
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$	MIN.	0.	.2	V		
I _H	I _T = 500 mA Gate open	MAX.	80		mA		
ΙL	I _G = 1.2 I _{GT}	MAX.	120		mA		
dV/dt	$V_D = 67 \% V_{DRM}$ Gate open $T_j = 125^{\circ} C$		MIN.	1000		V/µs	
V _{TM}	$I_{TM} = 80 \text{ A}$ $t_p = 380 \mu\text{s}$	T _i = 25° C		1.7		V	
V TM	$I_{TM} = 100 \text{ A}$ $t_p = 380 \mu\text{s}$	1	MAX.		1.7		
V _{t0}	Threshold voltage $T_j = 125^{\circ} \text{ C}$		MAX.	0.8	85	V	
R _d	Dynamic resistance	T _j = 125° C	MAX.	11	7	mΩ	
I _{DRM}	$V_{DRM} = V_{RRM}$ $T_j = 25^{\circ} C$		MAX.	20		μΑ	
I _{RRM}	VDRM = VRRM	T _j = 125° C	IVI/ T/X.	10		mA	

Table 5. Thermal reistances

Symbol	Parameter			Unit
R _{th(j-c)}	Junction to cope (AC)	MSS40	0.6	° C/W
	Junction to case (AC)	MSS50	0.45	C/VV

MSS40, MSS50 Characteristics

Figure 2. Maximum average power dissipation versus average on-state current

Figure 3. Average and DC on-state current versus case temperature

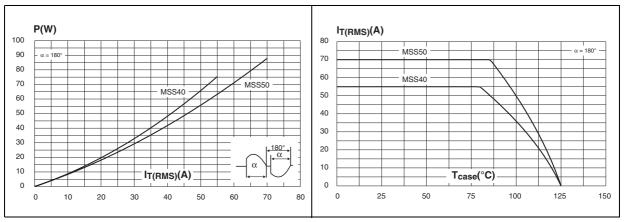


Figure 4. Relative variation of thermal impedance versus pulse duration

Figure 5. Relative variation of gate trigger current and holding current versus junction temperature

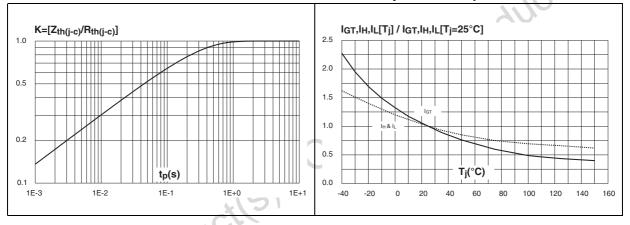
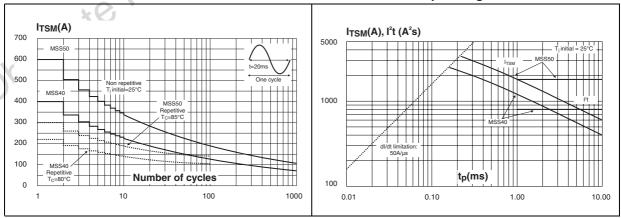


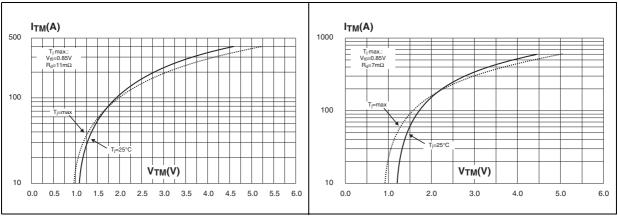
Figure 6. Surge peak on-state current versus Figure 7. number of cycles

Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10$ ms, and corresponding values of I^2t



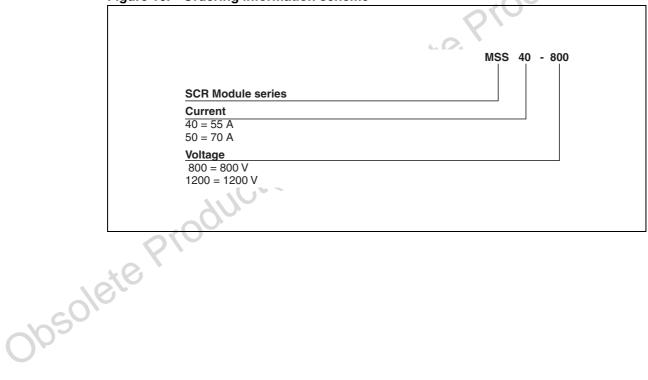
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Figure 8. On-state characteristics (maximum Figure 9. On-state characteristics (maximum values) (MSS40) values) (MSS50)



2 Ordering information scheme

Figure 10. Ordering information scheme

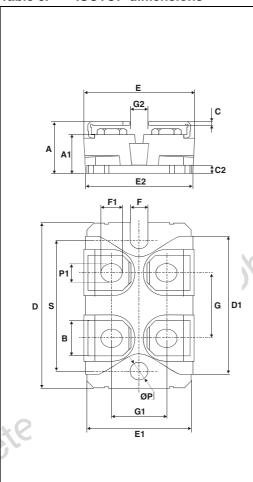


MSS40, MSS50 Package information

3 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.9 Nm (max. 1.2 Nm) for the 6 x M4 screws (2 x M4 screws recommended for mounting the package on the heatsink and the 4 provided screws).
- The screws supplied with the package are adapted for mounting on a board (or other types of terminals) with a thickness of 0.6 mm min. and 2.2 mm max.

Table 6. ISOTOP dimensions



	Dimensions					
Ref.	Millin	neters	Inches			
	Min. Max.		Min.	Max.		
Α	11.80	12.20	0.465	0.480		
A1	8.90	9.10	0.350	0.358		
В	7.8	8.20	0.307	0.323		
С	0.75	0.85	0.030	0.033		
C2	1.95	2.05	0.077	0.081		
D	37.80	38.20	1.488	1.504		
D1	31.50	31.70	1.240	1.248		
PE	25.15	25.50	0.990	1.004		
E1	23.85	24.15	0.939	0.951		
E2	24.80	0 typ.	0.976 typ.			
G	14.90	15.10	0.587	0.594		
G1	12.60	12.80	0.496	0.504		
G2	3.50	4.30	0.138	0.169		
F	4.10	4.30	0.161	0.169		
F1	4.60	5.00	0.181	0.197		
Р	4.00	4.30	0.157	0.69		
P1	4.00	4.40	0.157	0.173		
S	30.10	30.30	1.185	1.193		

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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Ordering information MSS40, MSS50

4 Ordering information

Table 7. Ordering information

Part number	Marking	Package	Weight	Base qty	Delivery mode
MSS40-1200	MSS40-1200		0.7	10	
MSS50-800	MSS50-800	ISOTOP	27 g (without screws)	10 (with screws)	Tube
MSS50-1200	MSS50-1200		(without sciews)	(mar corone)	

5 Revision history

Table 8. Revision history

	Date	Revision	Changes	115)	
	Sep-2000	3	Last release.		
	11-Jul-2007	4	Reformated to current standards. Removed MSS40-80	00 product.	
Obsole	11-Jul-2007 4 Reformated to current standards. Removed MSS40-800 product.				

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